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April 2014

FXL2T245

Low-Voltage, Dual-Supply, 2-Bit, Signal Translator with Configurable Voltage Supplies and Signal Levels and 3-State Outputs

Features

- Bi-Directional Interface between any 2 Levels from 1.1 V to 3.6 V
- Fully Configurable, Inputs Track V_{CC} Level
- Non-Preferential Power-up Sequencing; either V_{CC} maybe Powered-up First
- Outputs Remain in 3-State until Active V_{CC} Level is Reached
- Outputs Switch to 3-State if either V_{CC} is at GND
- Power-Off Protection
- Control Inputs (T/R, OE) Levels are Referenced to V_{CCA} Voltage
- Packaged in 10-Lead MicroPak
 (1.6 mm x 2.1 mm) Package
- ESD Protection Exceeds:
 - 4 kV HBM ESD JESD22-A114 & Mil Std 883e 3015.7)
 - 8kV HBM I/O to GND ESD (per JESD22-A114 & Mil Std 883e 3015.7)
 - 1 kV CDM ESD (per ESD STM 5.3)
 - 200 V MM ESD (per JESD22-A115 & ESD STM5.2)

Description

The FXL2T245 is a configurable, dual-voltage-supply translator designed for uni-directional and bi-directional voltage translation between two logic levels. The device allows translation between voltages as high as 3.6 V to as low as 1.1 V. The A port tracks the $V_{\rm CCA}$ level and the B port tracks the $V_{\rm CCB}$ level. This allows for bi-directional voltage translation over a variety of voltage levels: 1.2 V, 1.5 V, 1.8 V, 2.5 V, and 3.3 V.

The device remains in 3-state until both $V_{\rm CC}s$ reach active levels, allowing either $V_{\rm CC}$ to be powered-up first. Internal power-down control circuits place the device in 3-state if either $V_{\rm CC}$ is removed.

The Transmit / Receive (T/\overline{R}) input determines the direction of data flow through the device. The \overline{OE} input, when HIGH, disables both the A and B ports by placing them in a 3-state condition. The FXL2T245 is designed so control pins T/\overline{R} and \overline{OE} are supplied by V_{CCA} .

Ordering Information

Part Number	Operating Temperature Range	Package	Packing Method
FXL2T245L10X	-40°C to +85°C	10-Lead, MicroPak™, JEDEC MO255,1.6 x 2.1 mm	Tape and Reel

Pin Configuration

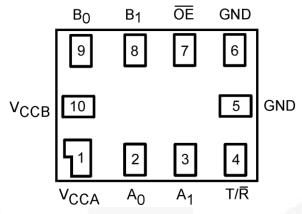


Figure 1. Pin Assignments

Pin Descriptions

Pin#	Pin Name	Description
1	V _{CCA}	Side A Power Supply
2	A ₀	Side A Inputs or 3-State Outputs
3	A ₁	Side A Inputs or 3-State Outputs
4	T/R	Transmit/Receive Input
5, 6	GND	Ground
7	Ō/E	Output Enable Input
8	B ₁	Side B Inputs or 3- State Outputs
9	B ₀	Side B Inputs or 3-State Outputs
10	V _{CCB}	Side B Power Supply

Truth Table

Inp	uts	Outputs		
ŌĒ	T/R			
LOW	LOW	Bus B Data to Bus A		
LOW	HIGH	Bus A Data to Bus B		

Notes:

- 1. LOW = low voltage level.
- 2. HIGH = high voltage level.

Functional Description

Power-Up / Power-Down Sequencing

Due to the chip design, the FXL2T245 translator offers the advantage of either V_{CC} being powered up first. When either V_{CC} is at 0 V, outputs are in a high-impedance state. The control inputs (T/R and $\overline{\text{OE}}$) are designed to track the V_{CCA} supply. A pull-up resistor tying $\overline{\text{OE}}$ to V_{CCA} should be used to ensure that bus contention, excessive currents, or oscillations do not occur during power-up/power-down. The size of the pull-up resistor is based upon the current-sinking capability of the $\overline{\text{OE}}$ driver.

The recommended power-up sequence is:

- 1. Apply power to either V_{CC} .
- 2. Apply power to the T/R input (logic HIGH for A-to-B operation; logic LOW for B-to-A operation) and to the respective data inputs (A port or B port). This may occur at the same time as step 1.
- 3. Apply power to the other V_{CC} .
- 4. Drive the OE input LOW to enable the device.

The recommended power-down sequence is:

- Drive OE input HIGH to disable the device.
- 2. Remove power from either V_{CC}.
- 3. Remove power from the other V_{CC}.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Conditions		Min.	Max.	Unit
V _{CCA}	Complet Valtage		-0.5	4.6	V	
V _{CCB}	Supply Voltage			-0.5	4.6	V
		I/O Port A		-0.5	4.6	
Vı	DC Input Voltage	I/O Port B		-0.5	4.6	V
		Control Inputs (T/R, OE)		-0.5	4.6	
		Output 3-State		-0.5	4.6	
Vo	Output Voltage(3)	Output Active (A _n)	. /	-0.5 to V _{CCA} 0.5		V
	/*	Output Active (B _n)		-0.5 to V _{CCB}	0.5	
I _{IK}	DC Input Diode Current	V ₁ < 0 V			-50	mA
	DC Output Diode Current	V _O < 0 V			-50	mA
I _{OK}	DC Output Diode Current	V _O > V _{CC}			+50	IIIA
I _{OH} /I _{OL}	DC Output Source/Sink Cu	rrent			±50	mA
I _{CC}	DC V _{CC} or Ground Current	per Supply Pin			±100	mA
T _{STG}	Storage Temperature Rang	e		-65	+150	°C
		Human Body Model,	All Pins		4	
ESD	Electrostatic Discharge	JESD22-A114, Mil Std 883e 3015.7	I/O to GND		8	kV
LSD	Capability	Charged Device Model, JESD22-C10		1		
		Machine Model, JESD22-A115,STM	5.2		200	V

Note

3. I/O absolute maximum ratings must be observed.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Conditions		Min.	Max.	Unit
V _{CC}	Power Supply	Operating \	V _{CCA} or V _{CCB}	1.1	3.6	V
		Port A		0	3.6	
V_{I}	Input Voltage	Port B		0	3.6	V
		Control Inp	uts (T/R, OE)	0	V_{CCA}	
			3.0 V to 3.6 V		±24	
			2.3 V to 2.7 V		±18	
I_{OH}/I_{OL}	Output Current	V _{CC}	1.65 V to 1.95 V		±6	mA
			1.40 V to 1.65 V		±2	
			1.1 V to 1.4 V		±0.5	
T _A	Operating Temperature, Free Air			-40	+85	°C
ΔV/Δt	Minimum Input Edge Rate	V _{CCA/B} =1.1	V to 3.6 V		10	ns/V

Note:

4. All unused inputs must be held at V_{CCI} or GND.

Electrical Characteristics

Symbol	Parameter	Conditions	V _{cco} (V)	V _{CCI} (V)	Min.	Max.	Unit
				2.70 to 3.60	2.00		
			2.30		1.60		
		Data Inputs An, Bn		1.65 to 2.30	0.65 x V _{CCI}		
				1.40 to 1.65	0.65 x V _{CCI}		
.,	HIGH Level		4 40 +- 0 00	1.10 to 1.40	0.90 x V _{CCI}		Ī ,,
V _{IH}	Input ⁽⁵⁾		1.10 to 3.60	2.70 to 3.60	2.00		\ \
				2.30 to 2.70	1.60		
		Control Pins /OE, T/R (Referenced to V _{CCA})		1.65 to 2.30	0.65 x V _{CCA}		
		(Helefeliced to VCCA)		1.40 to 1.65	0.65 x V _{CCA}		
				1.10 to 1.40	0.90 x V _{CCA}		
	1/2			2.70 to 3.60		0.80	
				2.30 to 2.70		0.70	
		Data Inputs An, Bn		1.65 to 2.30		0.35 x V _{CCI}	
				1.40 to 1.65	N.	0.35 x V _{CCI}	
.,	LOW Level		1.10 to 3.60	1.10 to 1.40		0.10 x V _{CCI}	1 ,,
V_{IL}	Input ⁽⁵⁾			2.70 to 3.60		0.80	V
, A		Control Pins /OE, T/R (Referenced to V _{CCA})		2.30 to 2.70		0.70	
				1.65 to 2.30		0.35 x V _{CCI}	
		(Helefeliced to ACCV)		1.40 to 1.65		0.35 x V _{CCI}	
				1.10 to 1.40		0.10 x V _{CCI}	
		Ι _{ΟΗ} = -100 μΑ	1.10 to 3.60	1.10 to 3.60	V _{CC0} - 0.20		
		I _{OH} = -12 mA	2.70	2.70	2.20		
		I _{OH} = -18 mA	3.00	3.00	2.40		
		I _{OH} = -24 mA	3.00	3.00	2.20		1
.,	HIGH Level	I _{OH} = -6 mA	2.30	2.30	2.00		Ī ,,
V _{OH}	Output ⁽⁶⁾	I _{OH} = -12 mA	2.30	2.30	1.80		\ V
		I _{OH} = -18 mA	2.30	2.30	1.70		
		I _{OH} = -6 mA	1.65	1.65	1.25		
		I _{OH} = -2 mA	1.40	1.40	1.05		
	1	$I_{OH} = -0.5 \text{ mA}$	1.10	1.10	0.75 x V _{CC0}		
		I _{OL} = 100 μA	1.10 to 3.60	1.10 to 3.60		0.20	
		I _{OL} = 12 mA	2.70	2.70	7	0.40	
		I _{OL} = 18 mA	3.00	3.00		0.40	
		I _{OL} = 24 mA	3.00	3.00		0.55	
V _{OL}	LOW Level Output ⁽⁶⁾	I _{OL} = 12 mA	2.30	2.30		0.40	V
	σαιραί	I _{OL} = 18 mA	2.30	2.30		0.60	1
		I _{OL} = 6 mA	1.65	1.65		0.30	1
		I _{OL} = 2 mA	1.40	1.40		0.35	1
	l H	$I_{OL} = 0.5 \text{ mA}$	1.10	1.10		0.30 x V _{CC0}	1

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Electrical Characteristics

Symbol	Parameter	Conditions	V _{cco} (V)	V _{CCI} (V)	Min.	Max.	Unit
IL	Input Leakage Current, Control Pins	V _I =V _{CCA} or GND	3.60	1.10 to 3.60		±1.0	μА
lass	Power Off	A_n , V_1 or V_0 =0 V to 3.6 V	3.60	0		±10	μΑ
loff	Leakage Current	B_n , V_I or $V_O=0$ V to 3.6 V	0	3.60		±10	
	3-State Output	A_n , B_n , $/OE=V_{IH}$	3.60	3.60		±10	μΑ
loz	Leakage $(0 \le V_0 \le 3.6 \text{ V},$	B _n , /OE= Don't Care ⁽⁷⁾	3.60	0		±10	
	V _I =V _{IH} or V _{IL})	A _n , /OE= Don't Care ⁽⁷⁾	0	3.60		±10	
I _{CCA/B}		V _I =V _{CCI} or GND; I _O =0	1.10 to 3.60	1.10 to 3.60		20	μΑ
I _{CCZ}		VI=VCCI OI GIND, IO=0	1.10 to 3.60	1.10 to 3.60		20	
1	Quiescent	V. V. a. or CND: I. O	1.10 to 3.60	0		-10	
I _{CCA}	Supply Current ⁽⁸⁾	V _I =V _{CCA} or GND; I _O =0	0	1.10 to 3.60		10	
. //		V V or CND. I O	0	1.10 to 3.60		-10	
I _{CCB}		$V_{I}=V_{CCB}$ or GND; $I_{O}=0$	1.10 to 3.60	0		10	
ΔIcca/B	Increase in I _{CC} per Input; Other Inputs at V _{CC} or GND	V _{IH} =3.0 V	3.60	3.60		500	μΑ

Notes:

- $$\begin{split} V_{\text{CCI}} &= \text{the } V_{\text{CC}} \text{ associated with the data input under test.} \\ V_{\text{CCO}} &= \text{the } V_{\text{CC}} \text{ associated with the output under test.} \end{split}$$
- Don't care = any valid logic level.
- Reflects current per supply, V_{CCA} or V_{CCB}.

AC Electrical Characteristics

		T _A = -40 to +85°C										
Symbol	Parameter		=3.0 V 3.6 V		=2.3 V 2.7 V		1.65 V .95 V		=1.4 V I.6 V		=1.1 V I.3V	Unit
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
V _{CCA} =3.0	V to 3.6 V			- //								
t _{PLH,} t _{PHL}	Propagation Delay A to B	0.2	3.5	0.3	3.9	0.5	5.4	0.6	6.8	1.4	22.0	ns
TPLH, TPHL	Propagation Delay B to A	0.2	3.5	0.2	3.8	0.3	4.0	0.5	4.3	0.8	13.0	115
+ +	Output Enable /OE to B	0.5	4.0	0.7	4.4	1.0	5.9	1.0	6.4	1.5	17.0	5
t _{PZH,} t _{PZL}	Output Enable /OE to A	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	ns
	Output Disable /OE to B	0.2	3.8	0.2	4.0	0.7	4.8	1.5	6.2	2.0	17.0	
t _{PHZ} , t _{PLZ}	Output Disable /OE to A	0.2	3.7	0.2	3.7	0.2	3.7	0.2	3.7	0.2	3.7	ns
V _{CCA} =2.3	V to 2.7 V								V			
	Propagation Delay A to B	0.2	3.8	0.4	4.2	0.5	5.6	0.8	6.9	1.4	22.0	
t _{PLH} , t _{PHL}	Propagation Delay B to A	0.3	3.9	0.4	4.2	0.5	4.5	0.5	4.8	1.0	7.0	ns
	Output Enable /OE to B	0.6	4.2	0.8	4.6	1.0	6.0	1.0	6.8	1.5	17.0	
t _{PZH} , t _{PZL}	Output Enable /OE to A	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	ns
	Output Disable /OE to B	0.2	4.1	0.2	4.3	0.7	4.8	1.5	6.7	2.0	17.0	
t _{PHZ,} t _{PLZ}	Output Disable /OE to A	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	ns
V _{CCA} =1.6	5 V to 1.95 V								/			
	Propagation Delay A to B	0.3	4.0	0.5	4.5	0.8	5.7	0.9	7.1	1.5	22.0	
t _{PLH} , t _{PHL}	Propagation Delay B to A	0.5	5.4	0.5	5.6	0.8	5.7	1.0	6.0	1.2	8.0	ns
	Output Enable /OE to B	0.6	5.2	0.8	5.4	1.2	6.9	1.2	7.2	1.5	18.0	
t _{PZH,} t _{PZL}	Output Enable /OE to A	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	ns
	Output Disable /OE to B	0.2	5.1	0.2	5.2	0.8	5.2	1.5	7.0	2.0	17.0	
t _{PHZ} , t _{PLZ}	Output Disable /OE to A	0.5	5.0	0.5	5.0	0.5	5.0	0.5	5.0	0.5	5.0	ns

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AC Electrical Characteristics

		T _A = -40 to +85°C										
Symbol	Parameter		=3.0 V 3.6 V		=2.3 V 2.7 V		1.65 V .95 V		=1.4 V .6 V		=1.1 V 1.3V	Unit
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
V _{CCA} =1.4	V to 1.6 V			- 14								
t _{PLH,} t _{PHL}	Propagation Delay A to B	0.5	4.3	0.5	4.8	1.0	6.0	1.0	7.3	1.5	22.0	ns
IPLH, IPHL	Propagation Delay B to A	0.6	6.8	0.8	6.9	0.9	7.1	1.0	7.3	1.3	9.5	115
tt_	Output Enable /OE to B	1.1	7.5	1.1	7.6	1.3	7.7	1.4	7.9	2.0	20.0	ns
t _{PZH} , t _{PZL}	Output Enable /OE to A	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	115
tphz. tplz	Output Disable /OE to B	0.4	6.1	0.4	6.2	0.9	6.2	1.5	7.5	2.0	18.0	20
IPHZ, IPLZ	Output Disable /OE to A	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	ns
V _{CCA} =1.1	V to 1.3 V											
	Propagation Delay A to B	0.8	13.0	1.0	7.0	1.2	8.0	1.3	9.5	2.0	24.0	no
t _{PLH} , t _{PHL}	Propagation Delay B to A	1.4	22.0	1.4	22.0	1.5	22.0	1.5	22.0	2.0	24.0	ns
t t	Output Enable /OE to B	1.0	12.0	1.0	9.0	2.0	10.0	2.0	11.0	2.0	24.0	no
t _{PZH} , t _{PZL}	Output Enable /OE to A	2.0	22.0	2.0	22.0	2.0	22.0	2.0	22.0	2.0	22.0	ns
t t	Output Disable /OE to B	1.0	15.0	0.7	7.0	1.0	8.0	2.0	10.0	2.0	20.0	nc
t _{PHZ,} t _{PLZ}	Output Disable /OE to A	2.0	15.0	2.0	12.0	2.0	12.0	2.0	12.0	2.0	12.0	ns

Capacitance

Symbol	Parameter	Conditions	T _A =+25°C	Unit	
Symbol	Parameter	Conditions	Typical	Offic	
C _{IN}	Input Capacitance (Pins O/E, TR)	$V_{CCA}=V_{CCB}=3.3 \text{ V}, V_I=0 \text{V or } V_{CCA/B}$	4	pF	
C _{I/O}	Input / Output Capacitance A _n , B _n Ports	$V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_I = 0 \text{V or } V_{CCA/B}$	5	pF	
C _{PD}	Power Dissipation Capacitance	$V_{CCA}=V_{CCB}=3.3 \text{ V}, V_{I}=0\text{V or } V_{CC}, f=10 \text{ MHz}$	20	pF	

AC Loadings and Waveforms

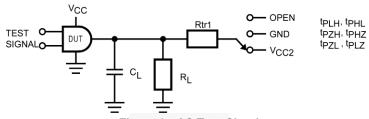
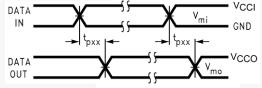


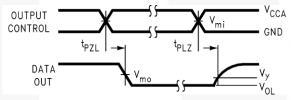
Figure 2. AC Test Circuit

Test	Switch
t _{PLH} ,t _{PHL}	Open
t _{PLZ} ,t _{PZL}	V_{CC0} • 2 at V_{CC0} =3.3 ±0.3 V, 2.5 V ±0.2 V, 1.8 V ±0.15 V, 1.5 V ±0.1 V, 1.2 V ±0.1 V
t _{PHZ} ,t _{PZH}	GND

Table 1. AC Load Table

1 4 5 1 1 1 1 1 5 1 5 1 4 5 1 4 5 1 5			
V _{cco}	C _L	R _L	Rtr1
1.2 V ±0.1 V	15 pF	2 kΩ	2 kΩ
1.5 V ±0.1 V	15 pF	2 kΩ	2 kΩ
1.8 V ±0.15 V	15 pF	2 kΩ	2 kΩ
2.5 V ±0.2 V	15 pF	2 kΩ	2 kΩ
3.3 V ±0.3 V	15 pF	2 kΩ	2 kΩ





Note:

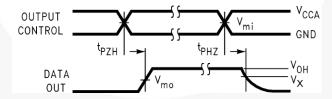
- 9. Input $t_R=t_F=2.0$ ns, 10% to 90%.
- 10. Input $t_{\text{R}}\text{-}t_{\text{F}}\text{=}2.5$ ns, 10% to 90%, at $V_{\text{I}}\text{=}3.0$ V to 3.6 V only.

Figure 3. Waveform for Inverting and Non-Inverting Functions

Note:

- 11. Input $t_R=t_F=2.0$ ns, 10% to 90%.
- 12. Input t_R - t_F =2.5 ns, 10% to 90%, at V_I =3.0 V to 3.6 V only.

Figure 4. 3-State Output Low Enable and Disable for Low Voltage Logic



Notes:

- 13. Input $t_R=t_F=2.0$ ns, 10% to 90%.
- 14. Input t_R - t_F =2.5 ns, 10% to 90%, at V_I =3.0 V to 3.6 V only.

Figure 5. 3-State Output High Enable and Disable for Low Voltage Logic

Symbol	Vcc				
Symbol	3.3 V ± 0.3 V	2.5 V ± 0.2 V	1.8 V ± 0.15 V	1.5 V ± 0.1 V	1.2 V ± 0.1 V
V _{MI}	V _{CCI} /2	V _{CCI} /2	V _{CCI} /2	V _{CCI} /2	V _{CCI} /2
V_{MO}	V _{CCO} /2	V _{CCO} /2	V _{CCO} /2	V _{CCO} /2	V _{CCO} /2
V _X	V _{OH} - 0.3 V	V _{OH} – 0.15 V	V _{OH} – 0.15 V	V _{OH} – 0.1 V	V _{OH} – 0.1 V
V _Y	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V	V _{OL} + 0.1 V	V _{OL} + 0.1 V

Note:

15. For V_{MI} $V_{CCO} = V_{CCA}$ for control pins T/\overline{R} and \overline{OE} or $V_{CCA}/2$.

Physical Dimensions

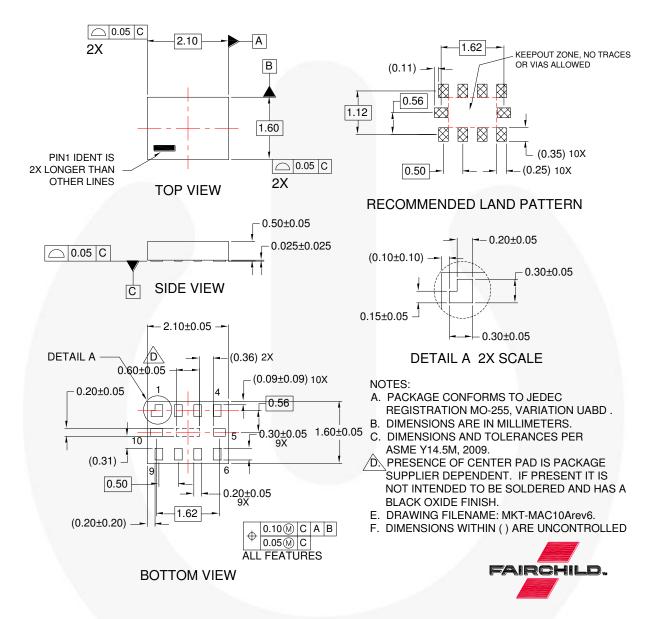


Figure 6. 10-Lead, MicroPak™, JEDEC MO255,1.6 x 2.1 mm

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